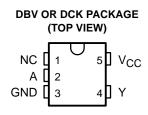
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- Operating Range 2-V to 5.5-V V<sub>CC</sub>
- Latch-Up Performance Exceeds 250 mA Per JESD 17

#### description

The SN74AHC1G14 contains one inverter gate. The device performs the Boolean function  $Y = \overline{A}$ .

The device functions as an independent inverter gate, but because of the Schmitt action, gates may have different input threshold levels for positive-  $(V_{T+})$  and negative-going  $(V_{T-})$  signals.



NC - No internal connection

#### **ORDERING INFORMATION**

TA	PACKAGE <sup>†</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING <sup>‡</sup>
–40°C to 85°C	SOT (SOT-23) – DBV	Tape and reel	SN74AHC1G14DBVR	A14_
-40 C 10 85 C	SOT (SC-70) – DCK	Tape and reel	SN74AHC1G14DCKR	AF_

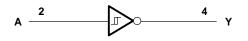
<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

<sup>‡</sup>The actual top-side marking has one additional character that designates the assembly/test site.

#### FUNCTION TABLE

INPUT A	OUTPUT Y
Н	L
L	Н

### logic diagram (positive logic)





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### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Supply voltage range, $V_{CC}$	5 V to 7 V C + 0.5 V -20 mA ±20 mA ±25 mA ±50 mA 206°C/W 252°C/W
Storage temperature range, T <sub>stg</sub> 65°C	to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51-7.

#### recommended operating conditions (see Note 3)

			MIN	MAX	UNIT
VCC	Supply voltage				V
VI	Input voltage				V
Vo	Output voltage		0	VCC	V
		$V_{CC} = 2 V$		-50	μΑ
ЮН	High-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		-4	mA
	$V_{CC}$ = 5 V ± 0.5 V			-8	IIIA
		$V_{CC} = 2 V$		50	μΑ
IOL	Low-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		4	mA
	$V_{CC}$ = 5 V ± 0.5 V			8	IIIA
Τ <sub>Α</sub>	Operating free-air temperature		-40	85	°C

NOTE 3: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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PARAMETER	TEST CONDITIONS	Vee	T	<b>₄ = 25°C</b>	;	MIN	МАХ	UNIT
PARAMETER	TEST CONDITIONS	Vcc	MIN	TYP	MAX	IVITIN		UNIT
V <sub>T+</sub>		3 V	1.2		2.2	1.2	2.2	v
Positive-going		4.5 V	1.75		3.15	1.75	3.15	
input threshold voltage		5.5 V	2.15		3.85	2.15	3.85	
V <sub>T</sub> _		3 V	0.9		1.9	0.9	1.9	
Negative-going		4.5 V	1.35		2.75	1.35	2.75	V
input threshold voltage		5.5 V	1.65		3.35	1.65	3.35	
		3 V	0.3		1.2	0.3	1.2	
$\Delta V_T$ Hysteresis (V <sub>T+</sub> – V <sub>T-</sub> )		4.5 V	0.4		1.4	0.4	1.4	V
		5.5 V	0.5		1.6	0.5	1.6	
		2 V	1.9	2		1.9		V
	I <sub>OH</sub> = -50 μA	3 V	2.9	3		2.9		
VOH		4.5 V	4.4	4.5		4.4		
	I <sub>OH</sub> = -4 mA	3 V	2.58			2.48		
	I <sub>OH</sub> = -8 mA	4.5 V	3.94			3.8		
		2 V			0.1		0.1	
	I <sub>OL</sub> = 50 μA	3 V			0.1		0.1	V
VOL		4.5 V			0.1		0.1	
	I <sub>OL</sub> = 4 mA	3 V			0.36		0.44	
	I <sub>OL</sub> = 8 mA	4.5 V			0.36		0.44	
lį	VI = 5.5 V or GND	0 V to 5.5 V			±0.1		±1	μA
ICC	$V_{I} = V_{CC} \text{ or GND},  I_{O} = 0$	5.5 V			1		10	μA
C <sub>i</sub>	$V_{I} = V_{CC}$ or GND	5 V		2	10		10	pF

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

# switching characteristics over recommended operating free-air temperature range, $V_{CC}$ = 3.3 V $\pm$ 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T <sub>A</sub> = 25	MIN	МАХ	UNIT	
FARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN TY	P MAX		WAA	UNIT
<sup>t</sup> PLH	٨	V	C <sub>L</sub> = 15 pF	8.	3 12.8	1	15	20
<sup>t</sup> PHL	A	I		8.	3 12.8	1	15	ns
<sup>t</sup> PLH	•	Y C <sub>L</sub> = 50 pF	0. 50 = 5	10.	3 16.3	1	18.5	
<sup>t</sup> PHL	A		10.	3 16.3	1	18.5	ns	

# switching characteristics over recommended operating free-air temperature range, $V_{CC}$ = 5 V $\pm$ 0.5 V (unless otherwise noted) (see Figure 1)

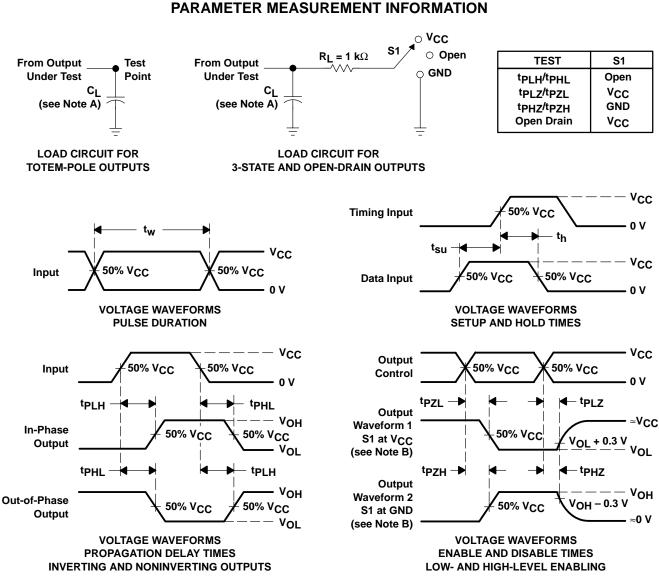
	PARAMETER	FROM	TO LOAD (OUTPUT) CAPACITANCE	T <sub>A</sub> = 25°C			MIN	мах	UNIT	
		(INPUT)		CAPACITANCE	MIN	TYP	MAX		UNIT	
Γ	<sup>t</sup> PLH	٨	V	C <sub>L</sub> = 15 pF		5.5	8.6	1	10	20
Γ	<sup>t</sup> PHL	A	T			5.5	8.6	1	10	ns
Γ	<sup>t</sup> PLH	٨	Y C <sub>L</sub> = 50 pF	V 0. 50 - 5		7	10.6	1	12	20
	<sup>t</sup> PHL	A			7	10.6	1	12	ns	



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## operating characteristics, $V_{CC} = 5 V$ , $T_A = 25^{\circ}C$

PARAMETER		TEST C	ONDITIONS	TYP	UNIT
C <sub>pd</sub>	Power dissipation capacitance	No load,	f = 1 MHz	9	pF



NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>f</sub>  $\leq$  3 ns, t<sub>f</sub>  $\leq$  3 ns.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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